### PNP -200mA -30V Digital Transistors (Bias Resistor Built-in Transistors)

Parameter	Value
V <sub>CC</sub>	-30V
I <sub>C(MAX.)</sub>	-200mA
R <sub>1</sub>	1.0k $\Omega$
$R_2$	10kΩ

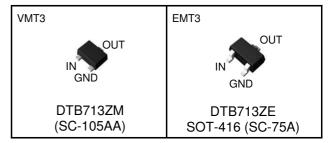
### ● Features

- 1) Built-In Biasing Resistors
- 2) Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see inner circuit).
- 3) The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input. They also have the advantage of completely eliminating parasitic effects.
- 4) Only the on/off conditions need to be set for operation, making the circuit design easy.
- 5) Complementary NPN Types :DTD713Z series
- 6) Lead Free/RoHS Compliant.

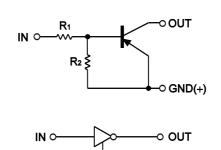
#### Application

Switching circuit, Inverter circuit, Interface circuit, Driver circuit

#### Outline



#### •Inner circuit



GND(+)

#### Packaging specifications

Part No.	Package	Package size (mm)	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit (pcs)	Marking
DTB713ZM	VMT3	1212	T2L	180	8	8,000	P11
DTB713ZE	EMT3	1616	TL	180	8	3,000	P11

## ● **Absolute maximum ratings** (Ta = 25 °C)

Parameter	Symbol	Values	Unit
Supply voltage	V <sub>CC</sub>	-30	V
Input voltage	V <sub>IN</sub>	−10 to +5	V
Collector current	I <sub>C(MAX.)</sub> *1	-200	mA
Power dissipation	$P_{D}^{*2}$	150	mW
Junction temperature	T <sub>j</sub>	150	∞
Range of storage temperature	T <sub>stg</sub>	−55 to +150	∞

## ●Electrical characteristics(Ta = 25 °C)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit	
length voltage	$V_{I(off)}$	$V_{CC} = -5V, I_{O} = -100 \mu A$	-	-	-0.3	V	
Input voltage	$V_{I(on)}$	$V_0 = -0.3V, I_0 = -20mA$	-2.5	-	1	v	
Output voltage	$V_{O(on)}$	$I_{O}/I_{I} = -50 \text{mA}/-2.5 \text{mA}$	-	-0.07	-0.3	V	
Input current	$I_1$	$V_1 = -5V$	-	-	-6.4	mA	
Output current	$I_{O(off)}$	$V_{CC} = -30V$ , $V_I = 0V$	-	-	-0.5	μΑ	
DC current gain	G <sub>I</sub>	$V_0 = -2V, I_0 = -100 \text{mA}$	140	-	1	-	
Input resistance	R <sub>1</sub>	-	0.7	1.0	1.3	kΩ	
Resistance ratio	R <sub>2</sub> /R <sub>1</sub>	-	8	10	12	-	
Transition frequency	f <sub>T</sub> *1	$V_{CE} = -10V, I_{E} = 5mA,$ f = 100MHz	-	260	1	MHz	

<sup>\*1</sup> Characteristics of built-in transistor

<sup>\*2</sup> Each terminal mounted on a reference footprint

#### ●Electrical characteristic curves(Ta = 25 °C)

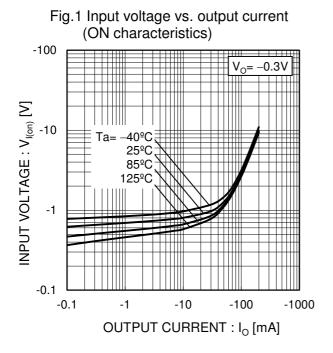


Fig.2 Output current vs. input voltage (OFF characteristics)

-100  $V_{CC} = -5V$   $T_{A} = 125^{\circ}C$   $S_{C} = -40^{\circ}C$ -0.1

-0.5

INPUT VOLTAGE:  $V_{I(off)}[V]$ 

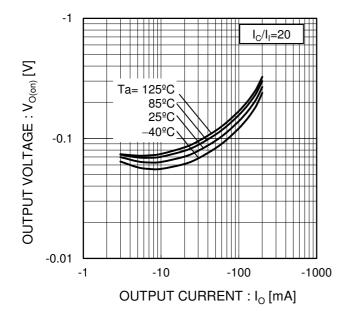
Fig.4 DC current gain vs. output current

Fig.3 Output current vs. output voltage

-200 1000 -1.0mA Ta=25ºC 0.9mA Ta= 125ºC 85ºC -0.8mA OUTPUT CURRENT: Io [mA] 25ºC -150 -0.7mA ഗ് 40ºC 100 -0.5mA -100 CURRENT 10 -0.3mA -50 -0.2mA -0.1mA 0 0A -2 0 -6 -1000 -10 -0.1 -1 -10 -100 OUTPUT VOLTAGE: Vo [V] OUTPUT CURRENT : Io [mA]

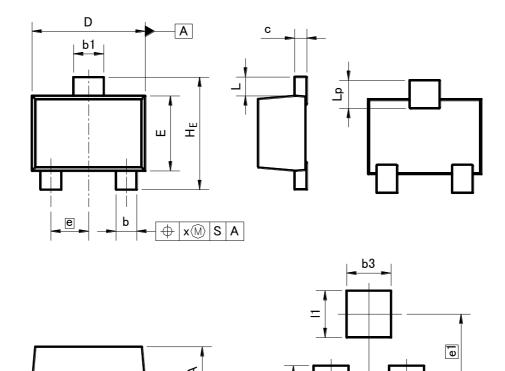
### ●Electrical characteristic curves(Ta = 25 °C)

Fig.5 Output voltage vs. output current



### ●Dimensions (Unit : mm)

#### VMT3



Pattern of terminal position areas
[Not a recommended pattern of soldering pads]

b2

DIM	MILIMETERS		INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	0.45	0.55	0.018	0.022	
A1	0.00	0.10	0.000	0.004	
b	0.17	0.27	0.007	0.011	
b1	0.27	0.37	0.011	0.015	
С	0.08	0.18	0.003	0.007	
D	1.10	1.30	0.043	0.051	
Е	0.70	0.90	0.028	0.035	
е	0.4	40	0.0	02	
HE	1.10	1.30	0.043	0.051	
L	0.10	0.30	0.004	0.012	
Lp	0.20	0.40	0.008	0.016	
х	_	0.10	_	0.004	

F

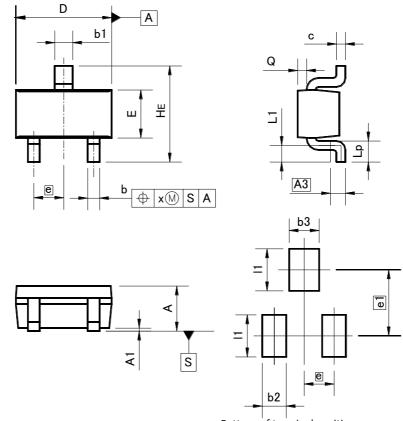
S

DIM	MILIMETERS		INCHES		
DIM	MIN MAX		MIN	MAX	
b2	I	0.37	ı	0.015	
b3	_	0.47	_	0.019	
e1	0.80		0.0	31	
l1	_	0.50	-	0.020	

Dimension in mm / inches

### ●Dimensions (Unit : mm)

#### **EMT3**



Pattern of terminal position areas [Not a recommended pattern of soldering pads]

DIM MILIM		ETERS	INC	INCHES	
DIM	MIN	MAX	MIN	MAX	
Α	0.60	0.80	0.024	0.031	
A1	0.00	0.10	0.000	0.004	
A3	0.:	25	0.0	10	
b	0.15	0.30	0.006	0.012	
b1	0.25	0.40	0.010	0.016	
С	0.10	0.20	0.004	0.008	
D	1.50	1.70	0.059	0.067	
Е	0.70	0.90	0.028	0.035	
е	0.	0.50 0.020		20	
HE	1.40	1.80	0.055	0.071	
L1	0.10	_	0.004	ı	
Lp	0.15	_	0.006		
Q	0.05	0.25	0.002	0.010	
х	_	0.10	_	0.004	

DIM	MILIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
b2	- 0.40		ı	0.016
b3	- 0.50		_	0.020
e1	1.10		0.0	43
l1		0.70		0.028

Dimension in mm / inches

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